

BSZ146N10LS5ATMA1

Data Sheet

OptiMOS [™] 5 power 1	MOSFETs logic level provide low RDS(on) in a small package	
Manufacturers	Infineon Technologies Corporation	
Package/Case	PG-TSDSON-8	11111
Product Type	Transistors	1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1
RoHS		
Lifecycle		Images are for reference only

Please submit RFQ for BSZ146N10LS5ATMA1 or Email to us: sales@ovaga.com We will contact you in 12 hours.

General Description

Infineon's OptiMOSTM 5 power MOSFETs logic level are highly suitable for wireless charging, adapter and telecom applications. The devices' low gate charge (Q g) reduces switching losses without compromising conduction losses. The improved figues of merit allow operations at high switching frequencies. Furthermore, the logic level drive provides a low gate threshold voltage (V GS(th)) allowing the MOSFETs to be driven at 5V and directly from microcontrollers.

Features

Low R DS(on) in small package

Low gate charge

Lower output charge

Logic level compatibility

Higher power density designs

Higher switching frequency

Reduced parts count wherever 5V supplies are available

Driven directly from microcontrollers (slow switching)

System cost reduction

Dolated Droducts

Ovaga Technologies Limited

Application

Wireless charging



BSP613P

Infineon Technologies Corporation SOT-223



BSB013NE2LXI

Infineon Technologies Corporation WDSON-2



BSC030N08NS5ATMA1 Infineon Technologies Corporation TDSON-8



BSC016N06NSATMA1 Infineon Technologies Corporation DSON-8









BSC011N03LS

Infineon Technologies Corporation PG-TDSON-8

BSC014N04LSATMA1

Infineon Technologies Corporation tdson-8

BSC026N08NS5ATMA1

Infineon Technologies Corporation TDSON-8

BSC066N06NSATMA1

Infineon Technologies Corporation TDSON-8